



## SIDC14D120E6

## Fast switching diode chip in EMCON-Technology

### **FEATURES:**

- 1200V EMCON technology 130 µm chip
- soft, fast switching
- low reverse recovery charge
- small temperature coefficient

## This chip is used for:

EUPEC power modules and discrete devices



## Applications:

SMPS, resonant applications, drives

Chip Type	$V_R$	I <sub>F</sub>	Die Size	Package	Ordering Code
SIDC14D120E6	1200V	15A	3.8 x 3.8 mm <sup>2</sup>	sawn on foil	Q67050-A4123- A001

### **MECHANICAL PARAMETER:**

<u></u>				
3.8 x 3.8				
14.44 / 9.8	mm <sup>2</sup>			
3.08 x 3.08				
130	μm			
150	mm			
180	deg			
1018 pcs				
Photoimide				
3200 nm AlSiCu				
1400 nm Ni Ag –system suitable for epoxy and soft solder die bonding				
electrically conductive glue or solder				
AI, ≤500μm				
Ø 0.65mm; max 1.2mm				
store in original container, in dry nitrogen, < 6 month at an ambient temperature of 23°C				
	14.44 / 9.8  3.08 x 3.08  130  150  180  1018 pcs  Photoimide  3200 nm AlSiCu  1400 nm Ni Ag —system suitable for epoxy and soft solder die bon electrically conductive glue or solder  Al, ≤500µm  Ø 0.65mm; max 1.2mm store in original container, in dry nitroge			



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## **Maximum Ratings**

Parameter	Symbol	Condition	Value	Unit	
Repetitive peak reverse voltage	$V_{RRM}$		1200	٧	
Continuous forward current limited by $T_{jmax}$	I <sub>F</sub>		15		
Single pulse forward current (depending on wire bond configuration)	I <sub>FSM</sub>	$t_P = 10 \; ms \; sinusoidal$	tbd	Α	
Maximum repetitive forward current limited by T <sub>jmax</sub>	I <sub>FRM</sub>		30		
Operating junction and storage temperature	$T_{\rm j}$ , $T_{ m stg}$		-55+150	°C	

## Static Electrical Characteristics (tested on chip), $T_j$ =25 °C, unless otherwise specified

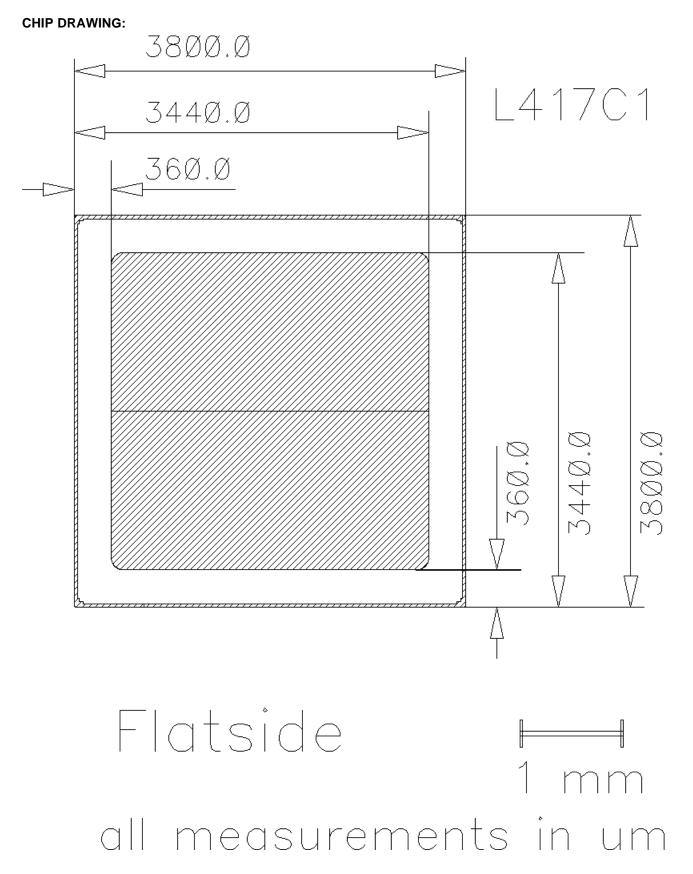
Parameter	Symbol	Cond	Value			Unit		
raiailietei	Syllibol	Cona	itions	min.	min. Typ. max.		]	
Reverse leakage current	$I_{R}$	V <sub>R</sub> =1200V	<i>T<sub>j</sub></i> =25 °C			250	μΑ	
Cathode-Anode breakdown Voltage	V <sub>Br</sub>	$I_R=1 mA$	<i>T<sub>j</sub></i> =25°C	1200			V	
Forward voltage drop	V <sub>F</sub>	I <sub>F</sub> =15A	<i>T<sub>j</sub></i> =25°C		1.9		V	

## **Dynamic Electrical Characteristics**, at $T_i = 25$ °C, unless otherwise specified, tested at component

Parameter	Symbol	Conditions		Value			Unit
	Syllibol			min.	Тур.	max.	7 01111
Reverse recovery time	t <sub>rr1</sub>	I <sub>F</sub> =15A	$T_j = 25$ °C		tbd		
	t <sub>rr2</sub>	di/dt=390A/ms $V_R=600V$	$T_j = 125$ °C				ns
Peak recovery current	I <sub>RRM1</sub>	$I_F=15A$ $di/dt=390A/ms$ $V_R=600V$	$T_j = 25$ °C		10.9		Α
	I <sub>RRM2</sub>		$T_j = 125$ °C		14.5		A
Reverse recovery charge	Q <sub>rr1</sub>	I <sub>F</sub> =15A di/dt=390A/ <b>m</b> s V <sub>R</sub> = 600V	<i>T<sub>j</sub></i> =25 °C		1.45		μC
	Q <sub>rr2</sub>		T <sub>j</sub> =125°C		3.23		7"~
Peak rate of fall of reverse recovery current	di <sub>rr1</sub> /dt	$I_F=15A$ di/dt=390A/ms $V_R=600V$	T <sub>j</sub> =25°C		tbd		A/μs
	di <sub>rr2</sub> /dt		T <sub>j</sub> =125°C				
Softness	S1	I <sub>F</sub> =15A	<i>T<sub>j</sub></i> =25 °C		tbd		1
	S2	di/dt=390A/ms $V_R=600V$	T <sub>j</sub> =125°C				<u> </u>



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## **Preliminary**

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#### **FURTHER ELECTRICAL CHARACTERISTICS:**

This chip data sheet refers to the device data sheet line infine on technologies / EUPEC today t

### **Description:**

AQL 0,65 for visual inspection according to failure catalog

Electrostatic Discharge Sensitive Device according to MIL-STD 883

Test-Normen Villach/Prüffeld

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